


APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

Title of Invention	[HIGH-K TUNNELING DIELECTRIC FOR READ ONLY MEMORY DEVICE AND FABRICATION METHOD THEREOF]		
Application Type : regular, utility Attorney Docket Number : 9946-US-PA-1			
Correspondence address: Customer Number: 31561 			
Continuing Data: This is a Division of US application number 10248179, filed 2002-12-24 , now pending.			
Inventor Information: <u>Inventor 1:</u> Applicant Authority Type: Inventor Citizenship: TW Name prefix: Mr. Given Name: Kent Kuohua Family Name: Chang Residence: City of Residence: Taipei Country of Residence: TW Address-1 of Mailing Address: 4 F., No. 66-1, Yen-Chi St., Address-2 of Mailing Address: City of Mailing Address: Taipei State of Mailing Address: Postal Code of Mailing Address: Country of Mailing Address: TW Phone: Fax: E-mail:			
Attorney Information: practitioner(s) at Customer Number:			

31561



as my attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.